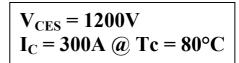
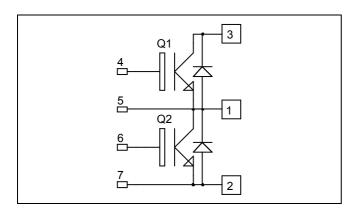


Phase leg Trench + Field Stop IGBT3 Power Module





Application

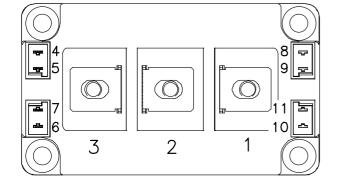
- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- High level of integration
- M6 power connectors



- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_{CEsat}
- RoHS Compliant



Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1200	V
I_{C}	Continuous Collector Current	$T_C = 25^{\circ}C$	440	
	Continuous Conector Current	$T_C = 80$ °C	300	A
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	600	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25$ °C	1450	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^{\circ}C$	600A @ 1100V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				500	μA
V	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		1.7	2.1	V
$V_{CE(sat)}$	Conector Emitter saturation voltage	$I_{\rm C} = 300 {\rm A}$	$T_j = 125$ °C		2.0		ľ
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 12mA$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V ; V_{CE} = 25V$ f = 1MHz			21		nF
C_{res}	Reverse Transfer Capacitance				1		111
Q_{G}	Gate charge	V _{GE} =±15V, I _C =300A V _{CE} =600V			2.8		μС
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ing (25°C)		250		
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$			90		
T _{d(off)}	Turn-off Delay Time	$V_{Bus} = 600V$ $I_{C} = 300A$			550		ns
T_{f}	Fall Time	$R_{\rm G} = 2.2\Omega$			130		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ing (125°C)		300		
T_{r}	Rise Time		$V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_{C} = 300A$ $R_{G} = 2.2\Omega$		100		ns
$T_{d(off)}$	Turn-off Delay Time				650		
$T_{\rm f}$	Fall Time	$R_G = 2.2\Omega$			180		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$T_j = 125$ °C		25		mJ
E_{off}	Turn off Energy	$I_C = 300A$ $R_G = 2.2\Omega$	$T_j = 125$ °C		44		1113
I_{sc}	Short Circuit data		$V_{GE} \le 15V$; $V_{Bus} = 900V$ $t_p \le 10\mu s$; $T_i = 125^{\circ}C$		1200		A

Reverse diode ratings and characteristics

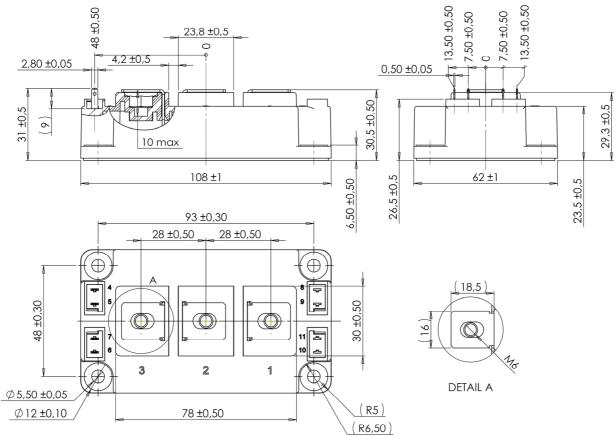
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I_{RRM}	Maximum Reverse Leakage Current	V _R =1200V	$T_i = 25$ °C $T_i = 125$ °C			750 1000	μΑ
I_{F}	DC Forward Current		$Tc = 80^{\circ}C$		300		A
V_{F}	Diode Forward Voltage	$I_F = 300A$	$T_i = 25^{\circ}C$		1.6	2.1	V
v F	Diode Forward Voltage	$V_{GE} = 0V$	$T_{i} = 125^{\circ}C$		1.6		v
+	Reverse Recovery Time	$I_F = 300 A$ $V_R = 600 V$ $di/dt = 3500 A/\mu s$	$T_j = 25^{\circ}C$		170		ng
t _{rr}			$T_j = 125$ °C		280		ns
0	Reverse Recovery Charge		$T_j = 25$ °C		28		C
Q_{rr}			$T_{j} = 125^{\circ}C$		56		μС
E _{rr}	Reverse Recovery Energy		$T_j = 25$ °C		12		mJ
L _{IT}			$T_{j} = 125^{\circ}C$		22		1113



Thermal and package characteristics

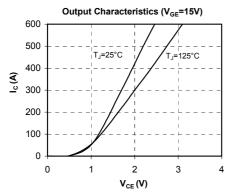
Symbol	Characteristic			Min	Тур	Max	Unit	
R_{thJC}	Junction to Case Thermal Resistance		IGBT			0.085	°C/W	
1\(\text{thJC}\)			Diode			0.16	C/ VV	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V	
T_{J}	Operating junction temperature range			-40		150		
T_{STG}	Storage Temperature Range Operating Case Temperature			-40		125	°C	
$T_{\rm C}$				-40		125		
Torque	Mounting torque	For terminals	M6	3		5	N.m	
		To Heatsink	M6	3		5	18.111	
Wt	Package Weight					350	g	

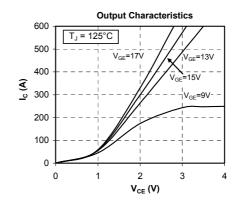
$D3\ Package\ outline\ ({\rm dimensions\ in\ mm})$

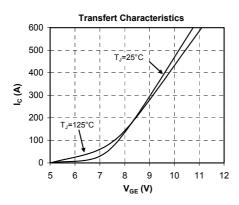


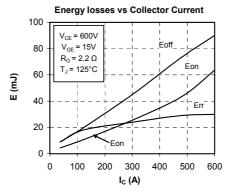


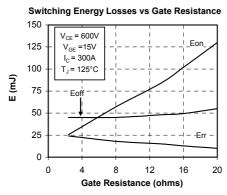
Typical Performance Curve

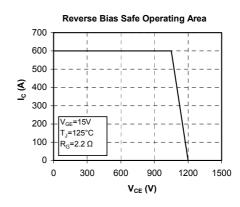


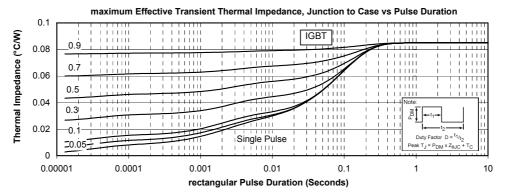




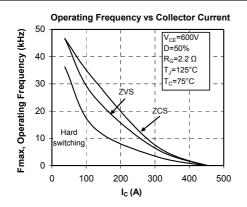


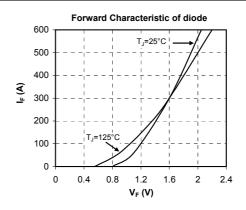


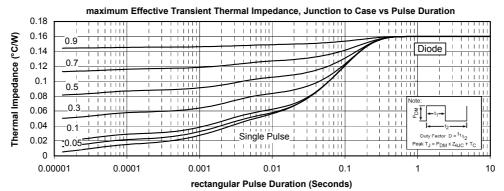














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